## NSN 5961-01-174-7980

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-174-7980 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.253 inches **Overall Width:** 0.500 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method:** Threaded stud Thready Qty Per Inch (tpi): **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 wire hook Shelf Life: N/a **Unit Of Measure: Demilitarization:** No